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INFORMATION DISCLOSURE				Filing Date	9/19/2003		
STA	TEMENT E	BY A	PPLICANT	ANT First Named Inventor Cho			
(Use as many sheets as necessary)				Art Unit	2818		
				Examiner Name	Tran, Mai Huong C		
Sheet	2	of	2	Attorney Docket Number	C002-D-2		

	0	NON PATENT LITERATURE DOCUMENTS						
Examiner Initials*	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.						
HH		Nemati, Farid and Plummer, James, D., A Novel High Density, Low Voltage SRAM Cell with a Vertical NDR Device, VLSI Technology Technical Digest, 6/1998						
MH	Nemati, Farid and Plummer, James, D., A Novel Thyristor-based SRAM Cell (T-RAM) for High-Speed, Low-Voltage, Giga-scale Memories, International Electron Device Meeting Technical Digest, 1999							
HH		Gribnikov, Z.S., Korobov, V.A., and Mitin, V.V., The Tunnel Didoe as a Thyristor Emitter, Solid-State Electronics, Vol. 42, No. 9, 1998, pp. 1761-1763						
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